

SEMICONDUCTORES Y COMPONENTES



2716 16K (2K x 8) UV ERASABLE PROM

- Fast Access Time
 - 2716-1: 350 ns Max — 2716-2: 390 ns Max — 2716: 450 ns Max
- Single +5V Power Supply
- Low Power Dissipation
 - Active Power: 525 mW MaxStandby Power: 132 mW Max

- Pin Compatible to Intel "Universal Site" EPROMs
- Simple Programming Requirements
 - Single Location Programming
 - Programs with One 50 ms Pulse
- Inputs and Outputs TTL Compatible During Read and Program
- **■** Completely Static

The Intel 2716 is a 16,384-bit ultraviolet erasable and electrically programmable read-only memory (EPROM). The 2716 operates from a single 5-volt power supply, has a static standby mode, and features fast single-address programming. It makes designing with EPROMs fast, easy and economical.

The 2716, with its single 5-volt supply and with an access time up to 350 ns, is ideal for use with high-performance +5V microprocessors such as Intel's 8085 and 8086. Selected 2716-5s and 2716-6s are also available for slower speed applications. The 2716 also has a static standby mode which reduces power consumption without increasing access time. The maximum active power dissipation is 525 mW while the maximum standby power dissipation is only 132 mW, a 75% savings.

The 2716 uses a simple and fast method for programming—a single TTL-level pulse. There is no need for high voltage pulsing because all programming controls are handled by TTL signals. Programming of any location at any time—either individually, sequentially or at random is possible with the 2716's single-address programming. Total programming time for all 16,384 bits is only 100 seconds.

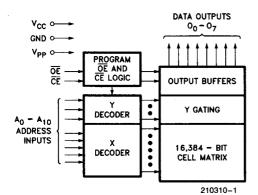


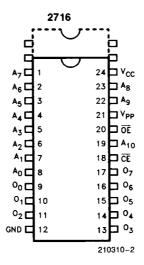
Figure 1. Block Diagram

Pin Names

A ₀ -A ₁₀	Addresses
CE	Chip Enable
ŌĒ	Output Enable
O ₀ -O ₇	Outputs



27512 27C512	27256 27C256	27128A 27C128		2732A
A ₁₅	V _{PP}	V _{PP}	Vpp	
A ₁₂	A ₁₂	A ₁₂	A ₁₂	
A ₇	A ₇	A ₇	A ₇	A ₇
A ₆	A ₆	A ₆	A ₆	A ₆
A ₅	A ₅	A ₅	A ₅	A ₅
A ₄	A ₄	A ₄	A ₄	A ₄
A ₃	A ₃	A ₃	A3	A ₃
A ₂	A ₂	A ₂	A ₂	A ₂
A ₁	Α1	A ₁	A ₁	A ₁
A ₀	A ₀	A ₀	A ₀	A ₀
00	00	00	00	00
O ₁	01	O ₁	01	01
02	02	02	02	02
GND	GND	GND	GND	GND



2732A		27128A	27256 27C256	27512 27C512
	V _{CC}	v_{cc}	Vcc	Vcc
	PGM	PGM	A ₁₄	A ₁₄
V _{CC}	N.C.	A ₁₃	A ₁₃	A ₁₃
A ₈				
A ₉	Ag	A ₉	A ₉	A ₉
A ₁₁				
OE/VPP	ŌĒ	ŌĒ	ŌĒ	OE/V _{PP}
A ₁₀				
CE	CE ALE/CE	CE	CE	CE
07	07	07	07	07
O ₆	06	06	06	06
O ₅	05	05	05	05
04	04	04	04	O ₄
03	03	03	03	О3

NOTE:

Intel "Universal Site" compatible EPROM configurations are shown in the blocks adjacent to the 2716 pins.

Figure 2. Cerdip Pin Configuration

EXTENDED TEMPERATURE (EXPRESS) EPROMS

The Intel EXPRESS EPROM family is a series of electrically programmable read only memories which have received additional processing to enhance product characteristics. EXPRESS processing is available for several densities of EPROM, allowing the choice of appropriate memory size to match system applications. EXPRESS EPROM products are available with 168 ±8 hour, 125°C dynamic burn-in using Intel's standard bias configuration. This process exceeds or meets most industry specifications of burn-in. The standard EXPRESS EPROM operating temperature range is 0°C to 70°C. Extended operating temperature range (-40°C to +85°C) EX-PRESS products are available. Like all Intel EPROMs, the EXPRESS EPROM family is inspected to 0.1% electrical AQL. This may allow the user to reduce or eliminate incoming inspection testing.

EXPRESS EPROM PRODUCT FAMILY

PRODUCT DEFINITONS

Туре	Operating Temperature	Burn-In 125°C (hr)
Q	0°C to +70°C	168 ±8
ı	-40°C to +85°C	44

EXPRESS OPTIONS

2716 Versions

Packaging Options				
Speed Versions	Cerdip			
<u> </u>	Q			
STD	Q, I			



DEVICE OPERATION

The six modes of operation of the 2716 are listed in Table 1. It should be noted that inputs for all modes are TTL levels. The power supplies required are a \pm 5V V_{CC} and a V_{PP} . The V_{PP} power supply must be at 25V during the three programming modes, and must be at 5V in the other three modes.

Read Mode

The 2716 has two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip Enable ($\overline{\text{CE}}$) is the power control and should be used for device selection. Output Enable ($\overline{\text{OE}}$) is the output control and should be used to gate data from the output pins, independent of device selection. Assuming that addresses are stable, address access time (t_{ACC}) is equal to the delay from $\overline{\text{CE}}$ to output (t_{CE}). Data is available at the outputs t_{OE} after the falling edge of $\overline{\text{OE}}$, assuming that $\overline{\text{CE}}$ has been low and addresses have been stable for at least t_{ACC} – t_{OE} .

Standby Mode

The 2716 has a standby mode which reduces the maximum active power dissipation by 75%, from 525 mW to 132 mW. The 2716 is placed in the standby mode by applying a TTL-high signal to the $\overline{\text{CE}}$ input. When in standby mode, the outputs are in a high impedance state, independent of the $\overline{\text{OE}}$ input.

Output OR-Tieing

Because 2716s are usually used in larger memory arrays, Intel has provided a 2-line control function that accommodates this use of multiple memory connections. The two-line control function allows for:

- a) the lowest possible memory power dissipation, and
- b) complete assurance that output bus contention will not occur.

To use these two control lines most efficiently, \overline{CE} (pin 18) should be decoded and used as the primary device selecting function, while \overline{OE} (pin 20) should be made a common connection to all devices in the array and connected to the \overline{READ} line from the system control bus. This assures that all deselected memory devices are in their low-power standby modes and that the output pins are active only when data is desired from a particular memory device.

Programming

Initially, and after each erasure, all bits of the 2716 are in the "1" state. Data is introduced by selectively programming "0's" into the desired bit locations. Although only "0's" will be programmed, both "1's" and "0's" can be presented in the data word. The only way to change a "0" to a "1" is by ultraviolet light erasure.

The 2716 is in the programming mode when the V_{PP} power supply is at 25V and \overrightarrow{OE} is at V_{IH} . The data to be programmed is applied 8 bits in parallel to the data output pins. The levels required for the address and data inputs are TTL.

When the address and data are stable, a 50 ms, active-high, TTL program pulse is applied to the $\overline{\text{CE}}$ input. A pulse must be applied at each address location to be programmed. You can program any location at any time—either individually, sequentially, or at random. The program pulse has a maximum width of 55 ms. The 2716 must not be programmed with a DC signal applied to the $\overline{\text{CE}}$ input.

Table 1. Mode Selection	Tab	ole :	1. N	loc	le S	ei	ect	ion
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, and the mode colourer					
Pins	CE	ŌĒ	V _{PP}	v _{cc}	Outputs
Mode	(18)	(20)	(21)	(24)	(9-11, 13-17)
Read	V _{IL}	V _{IL}	+5	+5	D _{OUT}
Output Disable	V _{IL}	V _{IH}	+5	+5	High Z
Standby	V _{IH}	X	+5	+5	High Z
Program	Pulsed V _{IL} to V _{IH}	V _{IH}	+ 25	+5	D _{IN}
Verify	V _{IL}	V _{IL}	+ 25	+5	D _{OUT}
Program Inhibit	V _{IL}	VIH	+ 25	+5	High Z

NOTE:

1. X can be VIL or VIH.



ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias -10° C to $+80^{\circ}$ C Storage Temperature -65° C to $+125^{\circ}$ C All Input or Output Voltages with Respect to Ground +6V to -0.3V V_{PP} Supply Voltage with Respect

to Ground During Program $\dots + 26.5V$ to -0.3V

NOTICE: This is a production data sheet. The specifications are subject to change without notice.

*WARNING: Stressing the device beyond the "Absolute Maximum Ratings" may cause permanent damage. These are stress ratings only. Operation beyond the "Operating Conditions" is not recommended and extended exposure beyond the "Operating Conditions" may affect device reliability.

D.C. AND A.C. OPERATING CONDITIONS DURING READ

	2716	2716-1	2716-2
Temperature Range	0°C-70°C	0°C−70°C	0°C-70°C
V _{CC} Power Supply ^(1, 2)	5 V ±5%	5V ±5%	5V ±5%
V _{PP} Power Supply ⁽²⁾	Vcc	Vcc	V _{CC}

READ OPERATION

D.C. CHARACTERISTICS

Symbol	Parameter	Limits			Units	Test Conditions
Cymbol	i di diliotoi	Min	Typ(3)	Max	OO	root containone
լը	Input Load Current			10	μΑ	$V_{IN} = 5.25V$
ILO	Output Leakage Current			10	μΑ	V _{OUT} = 5.25V
(PP1 (2)	V _{PP} Current			5	mA	$V_{PP} = 5.25V$
l _{CC1} ⁽²⁾	V _{CC} Current (Standby)		10	25	mA	CE = VIH, OE = VIL
I _{CC2} (2)	V _{CC} Current (Active)		57	100	mA	$\overline{OE} = \overline{CE} = V_{IL}$
V _{IL}	Input Low Voltage	-0.1		0.8	V	
V _{IH}	Input High Voltage	2.0		V _{CC} + 1	V	
V _{OL}	Output Low Voltage			0.45	V	I _{OL} = 2.1 mA
V _{OH}	Output High Voltage	2.4			V	$I_{OH} = -400 \mu\text{A}$

A.C. CHARACTERISTICS

	•			Test				
Symbol	Parameter	2716		2716-1		2716-2		Conditions†
		Min	Max	Min	Max	Min	Max	
tACC	Address to Output Delay		450		350		390	CE = OE = VIL
t _{CE}	CE to Output Delay		450		350		390	OE = V _{IL}
t _{OE} (4)	Output Enable to Output Delay		120		120		120	CE = V _{IL}
t _{DF} (4, 6)	CE or OE High to Output Float	0	100	0	100	0	100	CE = V _{IL}
t _{ОН}	Output Hold from Addresses, CE or OE Whichever Occurred First	0		0		0		CE = OE = V _{IL}

Programming of multiple 2716s in parallel with the same data can be easily accomplished due to the simplicity of the programming requirements. Like inputs of the paralleled 2716s may be connected together when they are programmed with the same data. A low level TTL pulse applied to the $\overline{\text{CE}}$ input programs the paralleled 2716s.

Program Inhibit

Programming of multiple 2716s in parallel with different data is also easily accomplished. Except for \overline{CE} , all like inputs (including \overline{OE}) of the parallel 2716s may be common. A TTL-level program pulse applied to a 2716's \overline{CE} input with V_{PP} at 25V will program that 2716. A low-level \overline{CE} input inhibits the other 2716 from being programmed.

Verify

A verify should be performed on the programmed bits to determine that they were correctly programmed. The verify may be performed with V_{PP} at 25V. Except during programming and program verify, V_{PP} must be at 5V.

ERASURE CHARACTERISTICS

The erasure characteristics of the 2716 are such that erasure begins to occur upon exposure to light with wavelengths shorter than aproximately 4000 Angstroms (Å). It should be noted that sunlight and certain types of fluorescent lamps have wavelengths in the 3000–4000Å range. Data show that constant exposure to room-level fluorescent lighting could erase the typical 2716 in approximately 3 years, while it would take approximately 1 week to cause erasure when exposed to direct sunlight. If the 2716 is to be exposed to these types of lighting conditions for extended periods of time, opaque labels should be placed over the window to prevent unintentional erasure.

The recommended erasure procedure for the 2716 is exposure to shortwave ultraviolet light which has a wavelength of 2537 Angstroms (Å). The integrated dose (i.e., UV intensity \times exposure time) for erasure should be a minimum of 15 Ws/cm². The erasure time with this dosage is approximately 15 to 20 minutes using an ultraviolet lamp with a 12000 $\mu W/cm^2$ power rating. The 2716 should be placed within 1 inch of the lamp tubes during erasure.

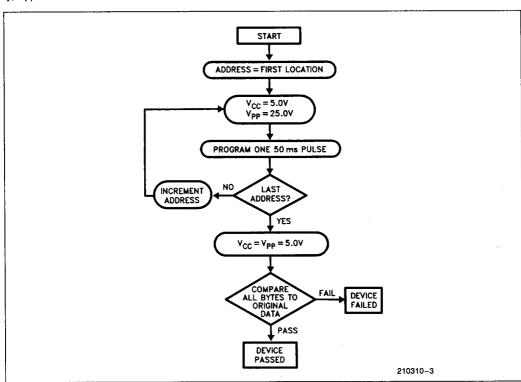


Figure 3. Standard Programming Flowchart



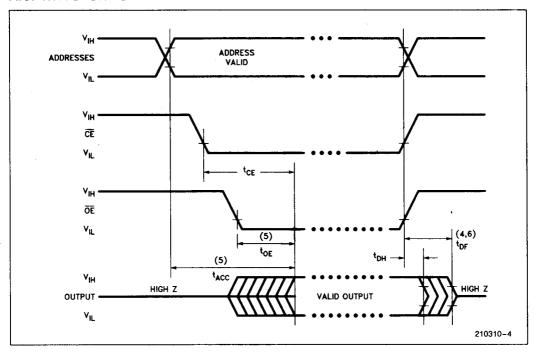
CAPACITANCE(4) TA = 25°C, f = 1 MHz

Symbol	Parameter	Тур(3)	Max	Unit	Test Conditions
CIN	Input Capacitance	4.	6	ρF	$V_{IN} = 0V$
C _{OUT}	Output Capacitance	8	12	pF	V _{OUT} = 0V

†A.C. TEST CONDITIONS

Output Load	1 TTL gate and C _i = 100 pF
Input Rise and Fall Times	- '
Input Pulse Levels	0.8V to 2.2V
Timing Measurement Refere	ence Level:
Inputs	0.8V and 2V
Outputs	

A.C. WAVEFORMS(1)



- 1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP}.

 2. V_{PP} may be connected to V_{CC} except during programming. The supply current would then be the sum of I_{CC} and I_{PP1}.

 3. Typical values are for T_A = 25°C and nominal supply voltages.

 4. This parameter is only sampled and is not 100% tested.

 5. OE may be delayed up to t_{ACC}-t_{OE} after the falling edge of CE without impact on t_{ACC}.

 6. t_{DF} is specified from OE or CE, whichever occurs first.

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PROGRAMMING CHARACTERISTICS

D.C. PROGRAMMING CHARACTERISTICS $T_A = 25^{\circ}C \pm 5^{\circ}C$, $V_{CC}^{(1)} = 5V \pm 5\%$, $V_{PP}^{(1,\,2)} = 25V \pm 1V$

Symbol	Parameter	Min	Тур	Max	Units	Test Conditions
L	Input Current (for Any Input)			10	μΑ	$V_{IN} = 5.25V/0.45$
I _{PP1}	V _{PP} Supply Current			5	mA	CE = V _{IL}
I _{PP2}	V _{PP} Supply Current during Programming Pulse			30	mA	CE = V _{IH}
Icc	V _{CC} Supply Current			100	mA	
V _{IL}	Input Low Level	-0.1		0.8	V	
V _{IH}	Input High Level	2.0		V _{CC} + 1	V	

A.C. PROGRAMMING CHARACTERISTICS $T_A = 25^{\circ}C \pm 5^{\circ}C$, $V_{CC}^{(1)} = 5V \pm 5^{\circ}$, $V_{PP}^{(1,2)} = 25V \pm 1V$

Symbol	Parameter	Min	Тур	Max	Units	Test Conditions*
t _{AS}	Address Setup Time	2			μs	
toes	OE Setup Time	2			μs	
t _{DS}	Data Setup Time	2			μs	
t _{AH}	Address Hold Time	2			μs	
^t OEH	OE Hold Time	2			μs	
t _{DH}	Data Hold Time	2			μs	
t _{DFP}	Output Enable to Output Float Delay	0		200	ns	$\overline{CE} = V_{IL}$
t _{OE}	Output Enable to Output Delay			200	ns	CE = VIL
tpW	Program Pulse Width	45	50	55	ms	
t _{PRT}	Program Pulse Rise Time	5			ns	
t _{PFT}	Program Pulse Fall Time	5			ns	

*A.C. CONDITIONS OF TEST

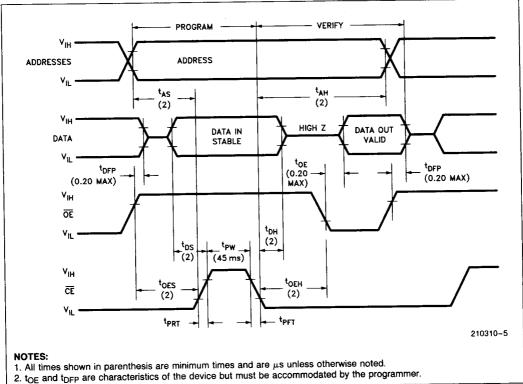
NOTES:

1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} . The 2716 must not be inserted into or removed from a board with V_{PP} at 25 \pm 1V to prevent damage to the device.

2. The maximum allowable voltage which may be applied to the V_{PP} pin during programming is $\pm 26V$. Care must be taken when switching the V_{PP} supply to prevent overshoot exceeding this 26V maximum specification.



PROGRAMMING WAVEFORMS



REVISION HISTORY

Number	Description				
03	Deleted -5 and -6 speed bins. Added Express options. Added Standard Programming Flowchart. Revised Pin Configuration and Block Diagram.				